

MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DS}	Drain to Source Voltage			30	V
V _{GS}	Gate to Source Voltage			±20	V
	Drain Current -Continuous (Package limited)	T _C = 25°C		80	
I _D	-Continuous (Silicon limited)	T _C = 25°C		219	Α
	-Pulsed		(Note 1)	556	
E _{AS}	Single Pulse Avalanche Energy		(Note 2)	673	mJ
PD	Power Dissipation			254	W
T _J , T _{STG}	Operating and Storage Temperature			-55 to +175	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case TO220	0.59	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient TO220	62	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP8860	FDP8860	TO220AB	Tube	N/A	50 units

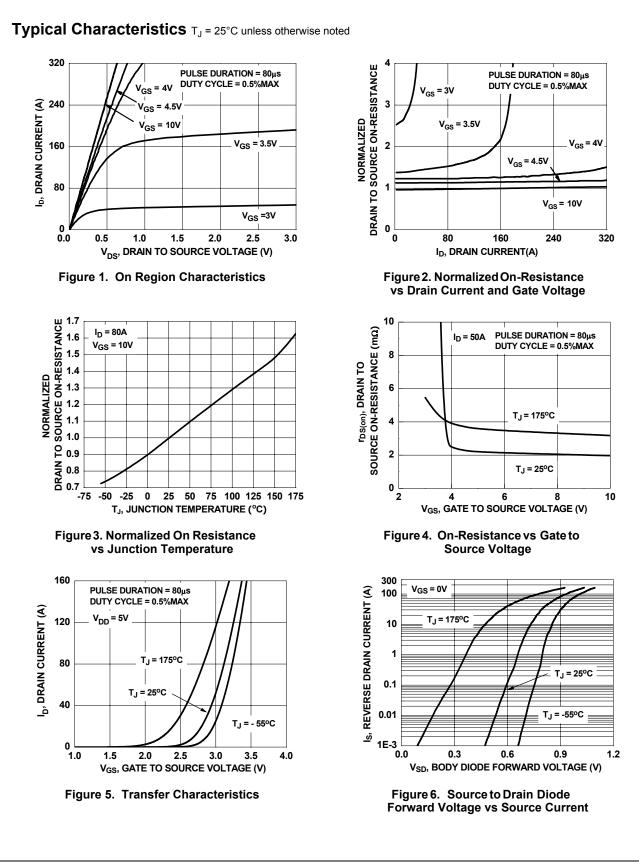
to

FDP8860
N-Channel
PowerTrench [®]
MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	acteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 1mA, V _{GS} = 0V	30			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 1mA, referenced to 25°C		22		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24V,$ $V_{GS} = 0V$ $T_{J} = 150^{\circ}C$			1 250	μA	
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20V			±100	nA	
	acteristics			- I	+	ł.	
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	1	1.6	2.5	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_{.l}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to 25°C		-9.6		mV/°C	
		V _{GS} = 10V, I _D = 80A		1.9	2.5		
r	Drain to Source On Registence	V _{GS} = 5V, I _D = 80A		2.0	2.8		
r _{DS(on)} Drain to	Drain to Source On Resistance	V _{GS} = 4.5V, I _D = 80A		2.1	2.9	mΩ	
		V _{GS} = 10V, I _D = 80A, T _J = 150°C	2.9 3.8		3.8		
9fs	Forward Transconductance	V _{DS} = 10V, I _D = 80A		3.4		S	
Dynamic	Characteristics						
C _{iss}	Input Capacitance			9200	12240	pF	
C _{oss}	Output Capacitance	──V _{DS} = 15V, V _{GS} = 0V, f = 1MHz		1700	2260	pF	
C _{rss}	Reverse Transfer Capacitance			1060	1590	pF	
R _g	Gate Resistance	f = 1MHz		1.7		Ω	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time			35	56	ns	
t _r	Rise Time	$V_{DD} = 15V, I_D = 80A$		135	216	ns	
t _{d(off)}	Turn-Off Delay Time	$-V_{GS}$ = 5V, R_{GEN} = 3 Ω		64	103	ns	
t _f	Fall Time			59	95	ns	
Q _{g(TOT)}	Total Gate Charge at 10V	$V_{GS} = 0V$ to 10V		158	222	nC	
Q _{g(5)}	Total Gate Charge at 5V	$\frac{V_{GS} = 0V \text{ to } 10V}{V_{GS} = 0V \text{ to } 5V} V_{DD} = 15V I_D = 80A$		81	114	nC	
Q _{gs}	Gate to Source Gate Charge	I _D = 80A		27		nC	
Q _{gd}	Gate to Drain "Miller" Charge			33		nC	
Drain-So	urce Diode Characteristics						
		V _{GS} = 0V, I _S = 80A		0.88	1.25		
V _{SD}	Source to Drain Diode Forward Voltage	V _{GS} = 0V, I _S = 40A		0.81	1.2	V	
t _{rr}	Reverse Recovery Time	I _F = 80A, di/dt = 100A/μs		60	90	ns	

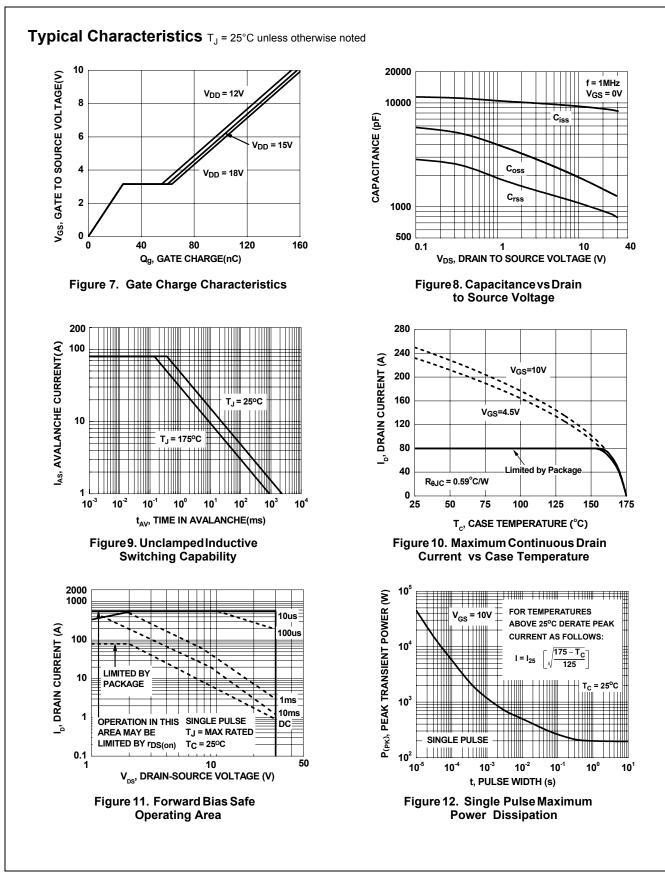
 Q_{rr}

Notes: 1: Pulse Test: Pulse Width < 80μ s, Duty cycle < 0.5%. **2:** Starting T_J =25°C, L= 0.3mH, I_{AS} = 67A, V_{DD} = 27V, V_{GS} = 10V.



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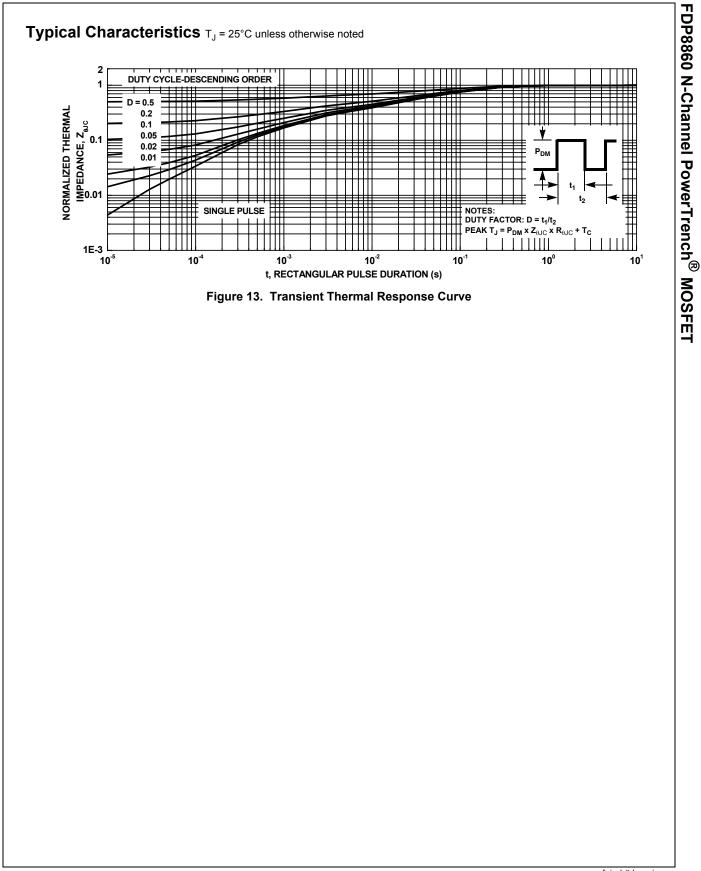




FDP8860 Rev.B

4

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